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List of Publications

1. *"Pressure induced superconducting state in ideal topological insulator $BiSbTe_3$"* **Vinod K. Gangwar** et al. *Phys. Scr.* ***96****, 055802 (2021).*

2. *"Anomalous and topological Hall effect in Cu doped Sb_2Te_3 topological insulator"* **Vinod K. Gangwar** et al. *Appl. Phys. Lett.* ***117****, 092403 (2020).*

3. *"Roles of surface and bulk states in magnetotransport properties in antiferromagnetically ordered $Bi_{1.9}Dy_{0.1}Te_3$ Topological insulator"* **Vinod K. Gangwar** et al. (*Under Review*).

4. *"Observation of antiferromagnetic ordering from muon spin resonance and Kondo effect in Dy doped Bi_2Se_3 topological insulator"* **Vinod K. Gangwar** et al. *J. Phys. D: Appl. Phys.* ***54****, 455302 (2021).*

5. *"Crystal growth and observation of large magnetoresistance (LMR) and SdH oscillations in $Ta_{1-x}Nb_xP$ Weyl semimetals"* **Vinod K. Gangwar** et al. (*To be communicated*).

6. *"Anomalous Hall effect in Cu doped Bi_2Te_3 topological insulator"* Abhishek Singh, Shiv Kumar, Mahima Singh, Prajyoti Singh, Rahul Singh, **Vinod K. Gangwar** et al. *J. Phys.: Condens. Matter* ***32,*** *305602 (2020).*

7. "*Evidence of surface and bulk magnetic ordering in Fe and Mn doped $Bi_2(SeS)_3$ topological insulator"* Mahima Singh, Shiv Kumar, Mohd Alam, **Vinod K. Gangwar** et al. *Appl. Phys. Lett.* ***118****, 132409 (2021).*

8. *"Defect induced ferromagnetic ordering and room temperature negative magnetoresistance in MoTeP"* Debarati Pal, Shiv Kumar, Prashant Shahi, Sambhab Dan, Abhineet Verma,**Vinod K. Gangwar** et al. *Sci. Rep.* ***11****, 9104 (2021).*

9. *"Unusual negative magnetoresistance in $Bi_2Se_{3-y}S_y$ topological insulator under perpendicular magnetic field"* Rahul Singh, **Vinod K. Gangwar** et al. *Appl. Phys. Letts.* ***112****, 102401 (2018).*

10. "*B-site disorder driven multiple-magnetic phases: Griffiths phase, re-entrant cluster glass, and exchange bias in Pr_2CoFeO_6"* Arkadeb Pal, Prajyoti Singh, **Vinod. K. Gangwar** et al. *Appl. Phys. Lett.* ***114****, 252403 (2019).*

11. *"Probing the Griffiths like phase, unconventional dual glassy states, giant exchange bias effects and its correlation with its electronic structure in $Pr_{2-x}Sr_xCoMnO_6$"*

Arkadeb Pal, Prajyoti Singh, **Vinod. K. Gangwar** et al. *J. Phys.: Condens. Matter* ***32,*** *215801, (2020).*

12. *"Investigation of multi-mode spin–phonon coupling and local B-site disorder in* Pr_2CoFeO_6 *by Raman spectroscopy and correlation with its electronic structure by XPS and XAS studies"* Arkadeb Pal, Surajit Ghosh, Amish G Joshi, Shiv Kumar, Swapnil Patil, Prince K Gupta, Prajyoti Singh, **Vinod K. Gangwar** et al. *J. Phys.: Condens. Matter* ***31****, 275802, (2019).*

13. *"Wasp – Waisted loop and spin frustration in* $Dy_{2-x}Eu_xTi_2O_7$ *pyrochlore"* Prajyoti Singh, Arkadeb Pal, **Vinod K. Gangwar** et al. *Jmmm,* ***518****, 167364, (2021).*

14. *"Roles of Re-entrant cluster glass state and spin–lattice coupling in magneto–dielectric behavior of giant dielectric double perovskite* $La_{1.8}Pr_{0.2}CoFeO_6$*"* P. Singh, Md. Alam, S. Kumar, K. Anand**, Vinod K. Gangwar** et al. *J. Phys.: Condens. Matter* ***32****, 445801, (2020).*

15. *"Spin freezing and field induced transition in* $(Tb_{1-x}Eu_x)_2Ti_2O_7$*: A magnetic property study"* Prajyoti Singh, Arkadeb Pal, **Vinod K. Gangwar** et al. *Jmmm,* ***490*** *, 165512, (2019).*

16. *"Shell Thickness-Dependent Tunable Threshold Voltage Single Quantum Dot Rectification Diode"* G. S. Kenath, R. Mahadevu, Anand Sharma, **Vinod K. Gangwar** et al. *J. Phys. Chem. C,* ***122****, 5, 3176–3181(2018).*

17. *"Single quantum dot rectifying diode with tunable threshold voltage"* Gopal S. Kenath, Piyali Maity, Yogesh Kumar, Hemant Kumar, **Vinod K. Gangwar** et al. *J. Mater. Chem. C,* ***5****, 9792-9798(2017).*

Schools / Meetings / Workshops / Conference Attended

1. 20th Symposium & Workshop on Thermal Analysis (THERMANS-2016), IIT BHU, VARANASI, INDIA.

2. 8th AONSA Neutron School (2016), BARC, TROMBAY, MUMBAI, INDIA.

3. Consortium Research Lecture Module, 1st Order Magnetic Phase Transitions and Some New Concepts (2017), UGC-DAE INDORE, INDIA.

4. International Conference on Advances in Biological System and Materials Science in Nano World (2017), IIT BHU, VARANASI, INDIA

5. The Indian Institute Of Metals (ICME-2017), IIT KANPUR, INDIA.

6. 10th National Conference on Solid State Chemistry and Allied Areas (ISCAS-2017), DTU, NEW DELHI, INDIA.

7. 62nd DAE Solid State Physics Symposium (2017), BARC, MUMBAI, INDIA.

8. National Conference on Advanced materials and Nanotechnology (AMN-2018) JIIT, NOIDA, INDIA.